

产品规格书

SPECIFICATIONS FOR PRODUCT

产品类型 TYPE : SMD3225

产品规格 SPEC : 32.768MHz/3225/10PF/10PPM AEC-Q200

产品型号 P/N : AD-CJ13-327681010C30

日期 DATE : 2022/04/02

| 核准及签名 | | | おりて |
|----------------------|------------------|----------------|---------|
| R&D APPR. SIGNATURED | | | DEPT. |
| 拟制 | 审核 | 批准 | 频率器件事业部 |
| ISSUE | CHECK | APPROVAL | |
| Ivan 2022/04/02 | Abbey 2022/04/02 | Ken 2022/04/02 | |

江 苏 长 晶 科 技 **股 份** 有 限 公 司 JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

地址:中国江苏省南京江北新区产业技术研创园江淼路88号腾飞大厦C座13楼Add: 13Th Floor, C Block, Tengfei Building, No. 88 Jiangmiao Rd. Pukou District, Nanjing City, Jiangsu Province, China



JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

SMCE3225 4 pads Crystal Resonator

AD-CJ13-327681010C30

1. Scope:

- 1.1 This specification applies to the RoHS/SONY compliance quartz crystal unit with a frequency of 32.768MHz which will be used in crystal oscillator applications.
- 1.2 AEC-Q200 qualified

2. Construction:

2.1 Type of Quartz Resonator: SMCE3225 4pads

3. Electrical Characteristics

3.1 Nominal Frequency(f): 32.768MHz

3.2 Load Capacitance(C_L): 10pF

3.3 Frequency Tolerance(△f/f): ±10ppm

3.4 Frequency Temperature Stability: ±30ppm(Ref.@25℃)

3.5 Resonance Resistance(ohm): 40ohms Max

3.6 Osc mode: Fundamental mode

3.7 Shunt Capacitance(C_0): <2pF

3.8 Drive Level(D_L): <100 μ W

3.9 Operating Temperature Range(T_{OPR}): -40 to + 105

3.10 Storage Temperature Range(T_{STG}): -55 to + 125°C

3.11 Insulation Resistance(IR): >500 M ohms

3.12 Aging($\triangle f_A$): ±3ppm per Year

1

4. Reliability Specifications

This is the quality control and quality assurance and reliability tests performance data for the RoHS/

AEC-Q200 compliance 32.768MHz SMCE3225 4pads crystal resonators

related to the specification and approval sheet provided by JSCJ.

Standard test condition (TEMP.: 20±5°C. Relative humidity: 65±20%)

For any discrepancy in GO/NG, test will be done at TEMP.25±2°C, R.H. 65±5%.

| NO. | PROCESS | SPECIFICATION | TEST METHOD |
|------|---------------------------------|---|--|
| 4.1 | Temperature Cycle | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms. | taken after DUT being left at room temperature for 24±2 hours. |
| 4.2 | High Temperature Storage | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms. | Spending 1000 hrs at 85°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.3 | Biased Humidity | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms. | Spending 1000 hrs at 85 °C \pm 3 °C, with 85%R.H, Then keep the DUT in dry oven at 25 \pm 5 °C for 24 hour. Measurement taken after DUT being left at room temperature for 1 to 2 hours. |
| 4.4 | Operational Life | 5ppm.Resonance resistance change after test ≤5ohms. | Spending 1000 hrs at 125°C±3°C constant temperature. Measurement taken after DUT being left at room temperature for 24±2 hours. |
| 4.5 | Vibration | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms. | Apply 1.52mm vibration at sweep frequency 10^{\sim} 2000Hz, 5g's for 20min 12 cycles in each direction of 3 axis. Measurement taken after 1 hour. |
| 4.6 | Mechanical Shock | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms.and exhibit no visible damage. | Peak 100gal, normal width 6ms half sine wave form, 3.7m/s, 3 cycles / direction. Measurement taken after 1 hour. |
| 4.7 | Solderability | Terminals shall be covered more then 95% with solder. | Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and soldering time for 20s ± 5s at 235°C, peak soldering time for 5s ±0.5s betweein 240 and 250°C. There is no need to do functional test. 8-12X magnifier. |
| 4.8 | Terminal Strength | No visible damage | Mount on a glass-epoxy board (100x50x1.6mm), then bend to 2mm displacement (velocity 1mm/sec) and keep for 5 seconds. or pulling force 1.8kg for at least 60 seconds. |
| 4.9 | Resistance to Soldering Heat | Frequency change after test ≤± 5ppm.Resonance resistance change after test ≤5ohms. | Passed through the re-flow oven under the following condition. Preheat 150 to 180°C for 60 to 120sec, and sodering time for 60s max at 235°C, peak soldering time for 10s max at 265°C max. Measurement taken after DUT being left at room temperature for at least 2 hours. |
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| | | | |
| 4.40 | OTUEDO | | |
| 4.10 | OTHERS | | |

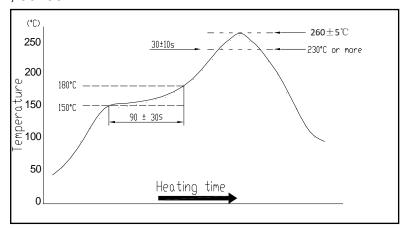
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Recommended Reflow soldering condition

5. Recommended Reflow soldering condition (SMD)

Solder profile

Peak: 260±5°C Soldering zone: 230°C or more, 30±10s. Pre-heating zone 1: 150 \sim 180°C, 90±30s



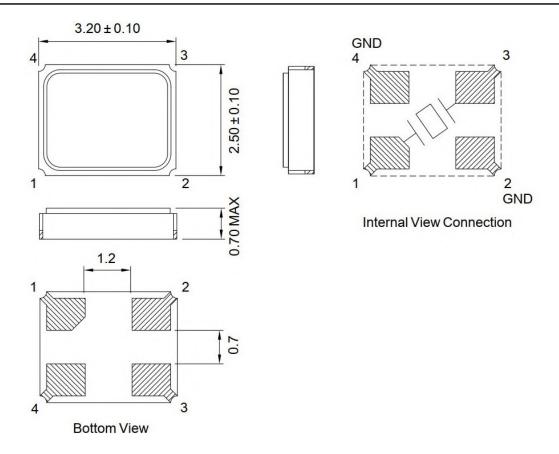
Temperature profile for reflow soldering

6. Soldering iron method

Bit temperature: 350±10°C Application time of soldering iron:3+1 s. For other procedures, refer to IEC 60068-2-20.

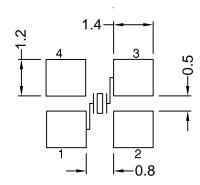
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Package Outline Dimensions



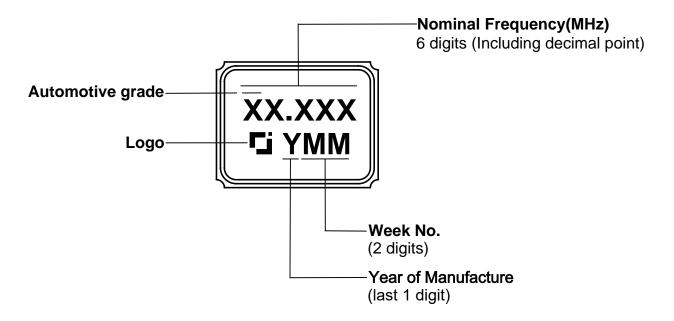
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Suggested Pad Layout

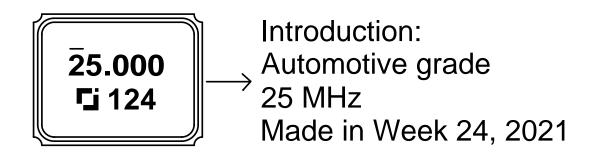


Marking

Procedure: Laser

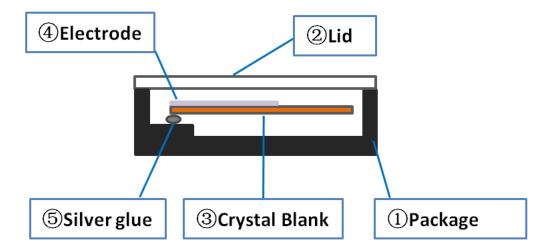


For example:

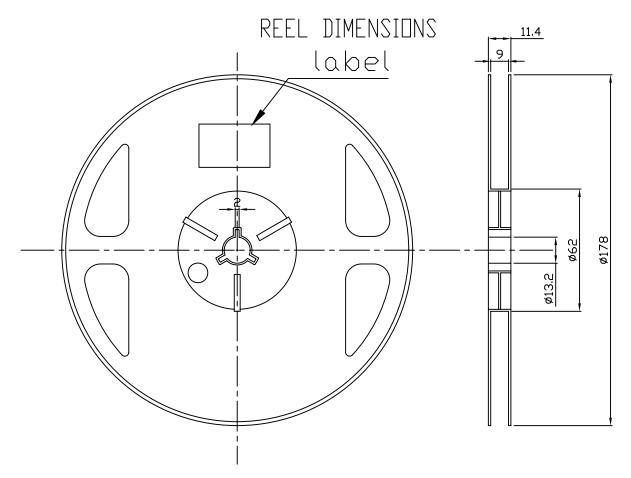


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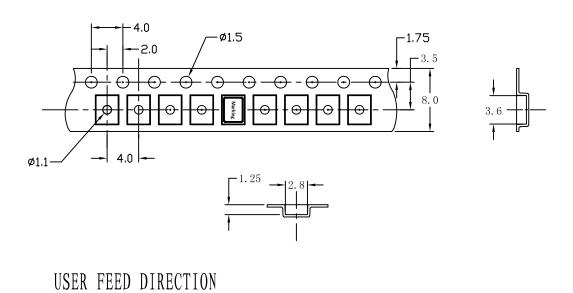
Inside Structure



| No. | Components | Materials |
|-----|---------------|--|
| 1 | Package | Ceramic(Al ₂ O ₃) |
| 2 | Lid | KV(Fe/Ni/Co) |
| 3 | Crystal blank | SiO ₂ |
| 4 | Electrode | Ag、Cr |
| 5 | Silver glue | Ag、CH₃OH、SiO₂ |

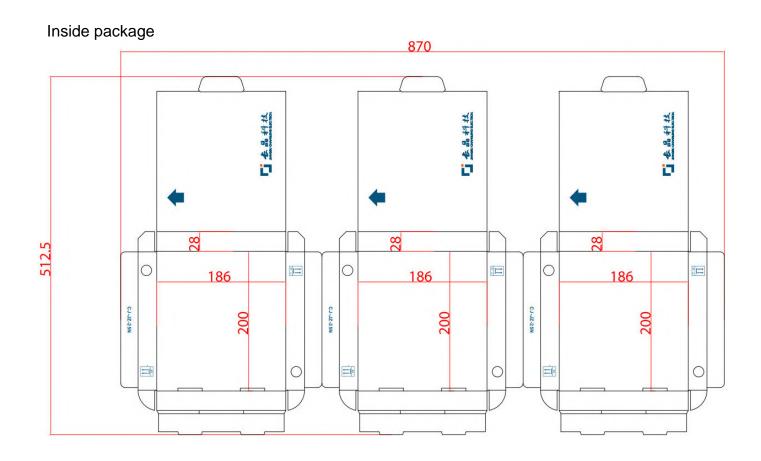


EMBOSSED TYPE DIMENSIONS

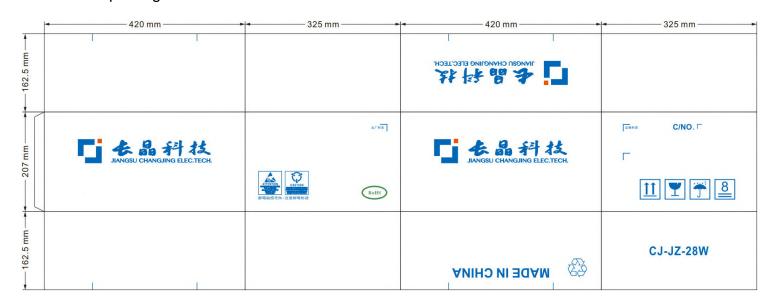


7

Package



Outside package



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